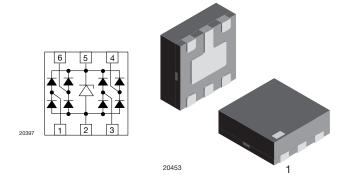
**GREEN** 

(5-2008)



# Vishay Semiconductors

### 4-Line BUS-Port ESD-Protection





Dot = Pin 1 marking

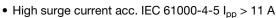
XX = Date code

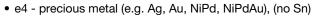
YY = Type code (see table below)

**MARKING** (example only)

#### **FEATURES**

- Ultra compact LLP75-6L package
- 4-line USB ESD-protection
- · Low leakage current
- Low load capacitance C<sub>D</sub> = 1.2 pF
- ESD-protection acc. IEC 61000-4-2
  ± 30 kV contact discharge
  - $\pm$  30 kV air discharge





 Material categorization: For definitions of compliance please see <a href="https://www.vishav.com/doc?99912">www.vishav.com/doc?99912</a>

ORDERING INFORMATION							
DEVICE NAME	ORDERING CODE	TAPED UNITS PER REEL (8 mm TAPE ON 7" REEL)	MINIMUM ORDER QUANTITY				
VBUS54CV-HSF	VBUS54CV-HSF-G4-08	3000	15 000				

PACKAGE DATA							
DEVICE NAME	PACKAGE NAME	TYPE CODE	WEIGHT	MOLDING COMPOUND FLAMMABILITY RATING	MOISTURE SENSITIVITY LEVEL	SOLDERING CONDITIONS	
VBUS54CV-HSF	LLP75-6L	UC	4.2 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	260 °C/10 s at terminals	

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	TEST CONDITIONS	SYMBOL	VALUE	UNIT		
Peak pulse current	Pin 1, 3, 4 or 6 to pin 2 acc. IEC 61000-4-5, t <sub>p</sub> = 8/20 μs/single shot	I	11	A		
	Pin 5 to pin 2 acc. IEC 61000-4-5; t <sub>p</sub> = 8/20 μs; single shot	Іррм	13	Α		
Peak pulse power	Pin 1, 3, 4 or 6 to pin 2 acc. IEC 61000-4-5, t <sub>p</sub> = 8/20 μs/single shot	P <sub>PP</sub>	242	W		
	Pin 5 to pin 2 acc. IEC 61000-4-5; t <sub>p</sub> = 8/20 μs; single shot	ГРР	246	VV		
ESD immunity	Contact discharge acc. IEC 61000-4-2; 10 pulses	$V_{ESD}$	± 30	kV		
	Air discharge acc. IEC 61000-4-2; 10 pulses	VESD	± 30	KV		
Operating temperature	Junction temperature	TJ	- 40 to + 125	°C		
Storage temperature		T <sub>STG</sub>	- 40 to + 150	°C		



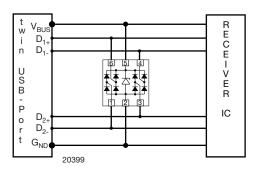
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<b>ELECTRICAL CHARACTERISTICS</b> (pin 1, 3, 4, or 6 to pin 2) (T <sub>amb</sub> = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITIONS/REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Protection paths	Number of lines which can be protected	N <sub>channel</sub>	-	-	4	lines	
Reverse stand-off voltage	Max. reverse working voltage	$V_{RWM}$	-	-	5.5	V	
Reverse voltage	at I <sub>R</sub> = 0.1 μA	$V_R$	5.5	-	-	V	
Reverse current	at V <sub>RWM</sub> = 5.5 V	I <sub>R</sub>	-	0.01	0.1	μΑ	
Reverse breakdown voltage	at I <sub>R</sub> = 1 mA	$V_{BR}$	7	7.9	8.6	V	
Reverse clamping voltage	at I <sub>PP</sub> = 11 A	V <sub>C</sub>	-	18	22	V	
Forward clamping voltage	at I <sub>PP</sub> =11 A	V <sub>F</sub>	-	6.5	8	V	
Capacitance	$V_R$ (at I/O pin) = 0 V $V_R$ (at pin 5) = 5 V; f = 1 MHz	C <sub>D</sub>	-	1.2	2.5	pF	
Line symmetry	Difference of the line capacitances	dC <sub>D</sub>	-	-	0.2	pF	

<b>ELECTRICAL CHARACTERISTICS</b> (pin 5 to pin 2) (T <sub>amb</sub> = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITIONS/REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Reverse stand-off voltage	Max. reverse working voltage	$V_{RWM}$	-	-	5.5	V	
Reverse voltage	at $I_R = 0.1 \mu A$ ; pin 2 to pin 1	V <sub>R</sub>	5.5	-	-	V	
Reverse current	at V <sub>RWM</sub> = 5.5 V	I <sub>R</sub>	-	0.01	0.1	μΑ	
Reverse breakdown voltage	at I <sub>R</sub> = 1 mA	$V_{BR}$	6.3	7.1	8	V	
Reverse clamping voltage	at I <sub>PP</sub> = 13 A	V <sub>C</sub>	-	18	22	V	
Forward clamping voltage	at I <sub>PP</sub> =13 A	V <sub>F</sub>	-	-	7	V	
Capacitance	V <sub>R</sub> (at pin 5) = 0 V; f = 1 MHz	C <sub>D</sub>	-	190	-	pF	

#### **APPLICATION NOTE**

With the VBUS54CV-HSF a double, high speed USB-port can be protected against transient voltage signals. Negative transients will be clamped close below the ground level while positive transients will be clamped close above the working range. An avalanche diode clamps the supply line ( $V_{BUS}$  at pin 5) to ground (pin 2). The high speed data lines,  $D_{1+}$ ,  $D_{2+}$ ,  $D_{1-}$  and  $D_{2-}$ , are connected to pin 1, 3, 4 and 6. As long as the signal voltage on the data lines is between the ground- and the  $V_{BUS}$ -level, the low capacitance PN-diodes offer a very high isolation to  $V_{BUS}$ , ground and to the other data lines. But as soon as any transient signal exceeds this working range, one of the PN-diodes gets in the forward mode and clamps the transient to ground or the avalanche break through voltage level.



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#### **TYPICAL CHARACHTERISTICS** (T<sub>amb</sub> = 25 °C, unless otherwise specified)

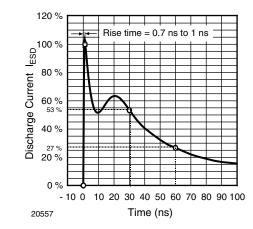


Fig. 1 - ESD Discharge Current Wave Form acc. IEC 61000-4-2 (330  $\Omega/150$  pF)

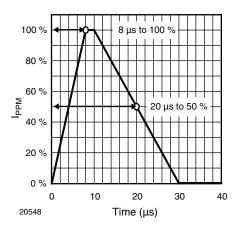


Fig. 2 - 8/20 µs Peak Pulse Current Wave Form acc. IEC 61000-4-5

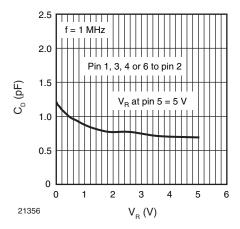


Fig. 3 - Typical Capacitance C<sub>D</sub> vs. Reverse Voltage V<sub>R</sub>

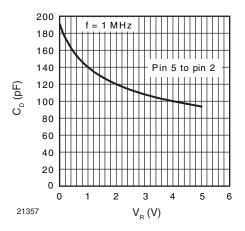


Fig. 4 - Typical Capacitance  $C_{\text{D}}$  vs. Reverse Voltage  $V_{\text{R}}$ 

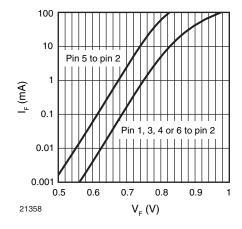


Fig. 5 - Typical Forward Current  $I_F$  vs. Forward current  $I_R$ 

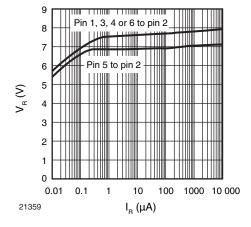


Fig. 6 - Typical Reverse Voltage V<sub>R</sub> vs. Reverse Current I<sub>R</sub>

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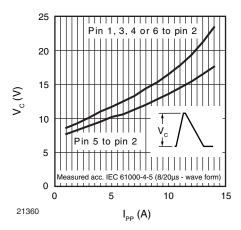


Fig. 7 - Typical Peak Clamping Voltage vs. Peak Pulse Current I<sub>PP</sub>

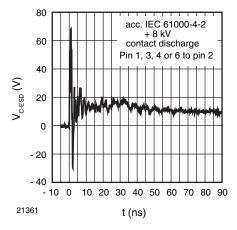


Fig. 8 - Typical Clamping Performance at 8 kV Contact Discharge (acc. IEC 61000-4-2)

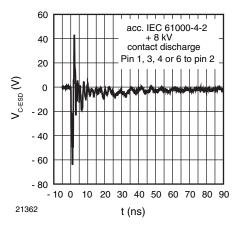


Fig. 9 - Typical Clamping Performance at 8 kV Contact Discharge (acc. IEC 61000-4-2)

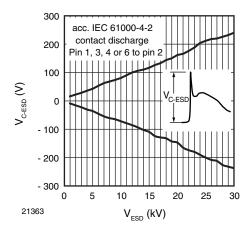
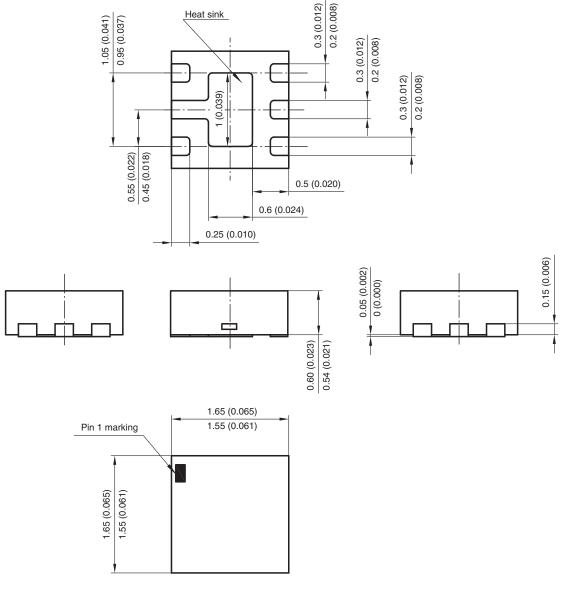


Fig. 10 - Typical Peak Clamping Voltage at ESD Contact Discharge (acc. IEC 61000-4-2)

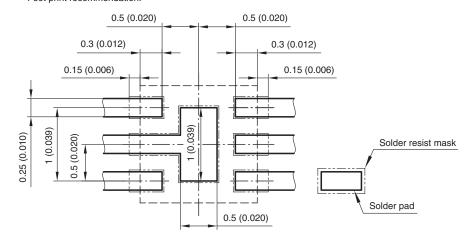
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#### PACKAGE DIMENSIONS in millimeters (inches) LLP75-6L



#### Foot print recommendation:



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